

# Matched GaAs SPDT Switch, DC-3.0 GHz with TTL/CMOS Control Input

M/A-COM Products
Rev. 6

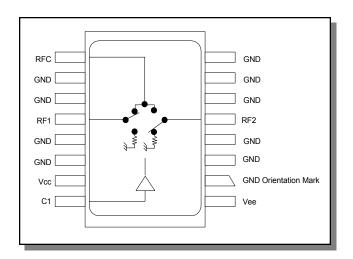
#### **Features**

- Integral TTL Driver
- Low DC Power Consumption
- Surface Mount Package
- Low Cost/High Performance
- 50 Ohm Nominal Impedance
- Lead-Free CR-9 Package
- 260°C Reflow Compatible
- RoHS\* Compliant

## **Description**

M/A-COM's SW10-0313 is a GaAs FET SPDT absorptive switch with integral silicon ASIC driver. Packaged in a 16-lead ceramic surface mount package, this device offers excellent performance and repeatability from DC to 3 GHz while maintaining low power consumption. The SW10-0313 is ideally suited for use where fast speed, low power consumption and broadband applications are required.

#### **Functional Block Diagram**



# **Ordering Information**

Part Number	Package	
SW10-0313	Bulk Packaging	
SW10-0313-TB	Sample Test Board	

Note: Reference Application Note M513 for reel size information.

#### **Pin Configuration**

Pin No.	Function	Pin No.	Function
1	Vee	9	RFC
2	GND	10	GND
3	GND	11	GND
4	GND	12	RF1
5	RF2	13	GND
6	GND	14	GND
7	GND	15	Vcc
8	GND	16	C1

The metal bottom of the case must be connected to RF and DC ground.

<sup>\*</sup> Restrictions on Hazardous Substances, European Union Directive 2002/95/EC.

**ADVANCED:** Data Sheets contain information regarding a product M/A-COM is considering for development. Performance is based on target specifications, simulated results, and/or prototype measurements. Commitment to develop is not guaranteed.

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Electrical Specifications:  $T_A = +25^{\circ}C^{1,2}$ 

Parameter	Test Conditions	Frequency	Units	Min	Тур	Max
Insertion Loss	_	DC - 3000 MHz DC - 2000 MHz DC - 1000 MHz DC - 500 MHz	dB dB dB dB		0.8 0.7 0.7 0.6	1.2 1.1 0.9 0.8
VSWR	_	DC - 3000 MHz DC - 2000 MHz DC - 1000 MHz DC - 500 MHz	Ratio Ratio Ratio Ratio	_ _ _ _	1.2:1 1.2:1 1.2:1 1.1:1	1.4:1 1.35:1 1.35:1 1.3:1
Isolation	_	DC - 3000 MHz DC - 2000 MHz DC - 1000 MHz DC - 500 MHz	dB dB dB dB	35 45 45 50	40 50 50 55	
Trise, Tfall	10% to 90%	_	ns		50	_
Ton, Toff	1.3V CTL to 90% / 10%	_	ns	1	150	_
Transients	In-Band	_	mV	1	50	-
1 dB Compression	Input Power	0.05 GHz 0.5 GHz to 3 GHz	dBm dBm	_ _	+25 +30	_
IP2	Two-Tone Input Power up to +5 dBm	0.05 GHz 0.5 GHz to 3 GHz	dBm dBm		+60 +65	
IP3	Two-Tone Input Power up to +5 dBm	0.05 GHz 0.5 GHz to 3 GHz	dBm dBm		+40 +46	
Vin Low	0V to 0.8V	_	μΑ	_	_	1
Vin High	2.0V to 5.0V		μΑ			1
Vcc	+5.0V ± 10%	_	mA	_	_	1
Vee	-5.0V to -8.0V	_	mA	_	_	1

<sup>1.</sup> All specifications apply when operated with bias voltages of +5V for Vcc and -5V for Vee.

# Absolute Maximum Ratings 3,4

Parameter	Absolute Maximum
Max Input Power 50 MHz 500 - 3000 MHz	+27 dBm +34 dBm
V <sub>CC</sub>	-0.5V ≤ V <sub>CC</sub> ≤ +7.0V
V <sub>EE</sub>	-8.5V ≤ V <sub>EE</sub> ≤ +0.5V
V <sub>CC</sub> - V <sub>EE</sub>	$-0.5V \le V_{CC} - V_{EE} \le 14.5V$
Vin <sup>5</sup>	-0.5V ≤ Vin ≤ V <sub>CC</sub> + 0.5V
Operating Temperature	-40°C to +125°C
Storage Temperature	-65°C to +150°C

<sup>3.</sup> Exceeding any one or combination of these limits may cause permanent damage to this device.

<sup>2.</sup> When DC blocks are used, a 10K ohm return to GND is required on the RFC port.

M/A-COM does not recommend sustained operation near these survivability limits.

Standard CMOS TTL interface, latch-up will occur if logic signal is applied prior to power supply.

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## **Handling Procedures**

Please observe the following precautions to avoid damage:

#### **Static Sensitivity**

Gallium Arsenide Integrated Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.

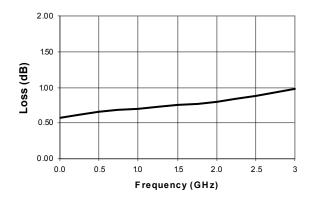
### **Truth Table (Switch)**

	Condition of Switch		
	RF Common to Each RF Port		
C1	RF1	RF2	
0	On	Off	
1	Off	On	

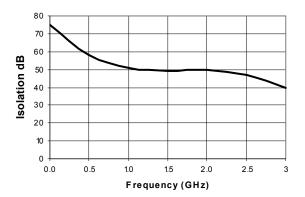
0 = TTL Low; 1 = TTL High

## **Typical Performance Curves**

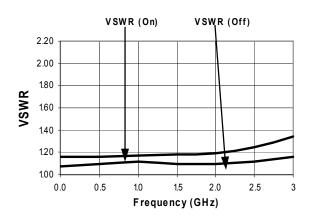
#### Insertion Loss vs. Frequency



#### Isolation vs. Frequency



#### VSWR vs. Frequency



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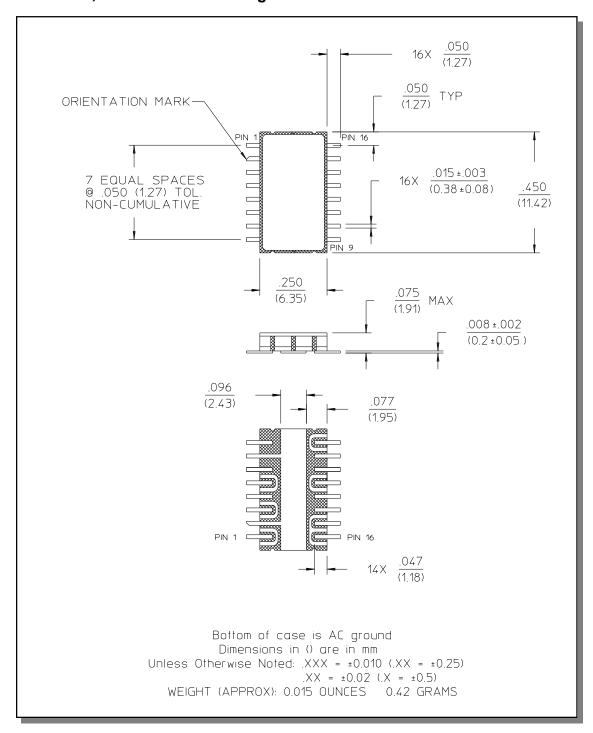
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## Lead-Free, CR-9 Ceramic Package<sup>†</sup>



<sup>&</sup>lt;sup>†</sup> Reference Application Note M538 for lead-free solder reflow recommendations.

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